

LSIC2SD120C05









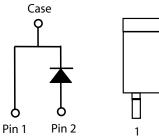
Description

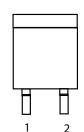
This series of silicon carbide (SiC) Schottky diodes has negligible reverse recovery current, high surge capability, and a maximum operating junction temperature of 175 °C. These diodes series are ideal for applications where improvements in efficiency, reliability, and thermal management are desired.

Features

- Positive temperature coefficient for safe operation and ease of paralleling
- 175 °C maximum operating junction temperature
- Excellent surge capability
- · Extremely fast, temperature-independent switching behavior
- Dramatically reduced switching losses compared to Si bipolar diodes

Circuit Diagram TO-252-2L (DPAK)





Applications

- Boost diodes in PFC or DC/DC stages
- Switch-mode power supplies
- Uninterruptible power supplies
- · Solar inverters
- Industrial motor drives
- EV charging stations

Environmental

- Littelfuse "RoHS" logo = RoHS RoHS conform
- Littelfuse "HF" logo = HF Halogen Free
- Littelfuse "PB-free" logo = (Pg) PB--free lead plating

Maximum Ratings

Characteristics	Symbol	Conditions	Value	Unit	
Repetitive Peak Reverse Voltage	V _{RRM}	-	1200	V	
DC Blocking Voltage	V _R	T _j = 25 °C	1200	V	
		T _c = 25 °C	18.1		
Continuous Forward Current	I _F	T _c = 135 °C	8.7	А	
		T _C = 159 °C	5		
Non-Repetitive Forward Surge Current	FSM	$T_C = 25 ^{\circ}\text{C}, T_P = 10 \text{ms}, \text{Half sine pulse}$	40	А	
Power Dissipation	P _{Tot}	T _c = 25 °C	100	W	
rowel Dissipation		T _C = 110 °C	43.3		
Operating Junction Temperature	T _J	-	-55 to 175	°C	
Storage Temperature	T _{STG}	-	-55 to 150	°C	
Soldering Temperature (reflow MSL 1)	T _{sold}	-	260	°C	

GEN2 SiC Schottky Diode LSIC2SD120C05, 1200 V, 5 A, TO-252-2L (DPAK)

Electrical Characteristics

		Conditions	Value				
Characteristics	Symbol		Min.	Тур.	Max.	Unit	
Forward Voltage	\/	I _F = 5 A, T _J = 25 °C	-	1.5	1.8	V	
	V _F	I _F = 5 A, T _J = 175 °C	-	2.1			
Reverse Current	I _R	V _R = 1200 V, T _J = 25 °C	-	<1	100	μΑ	
		V _R = 1200 V , T _J = 175 °C	-	5			
Total Capacitance	С	V _R = 1 V, f =1 MHz	-	310			
		V _R = 400 V, f = 1 MHz	-	29		pF	
		V _R = 800 V, f = 1 MHz	-	21			
Total Capacitive Charge	O _c	$V_R = 800 \text{ V}, \ \ Q_C = \int\limits_0^C C(V) dV$	-	30		nC	

Footnote: T₁ = +25 °C unless otherwise specified

Thermal Characteristics

Characteristics	Symbol Conditions		Value			
		Min.	Тур.	Max.	Unit	
Thermal Resistance	R _{euc}	-	-	1.50		°C/W

Figure 1: Typical Foward Characteristics

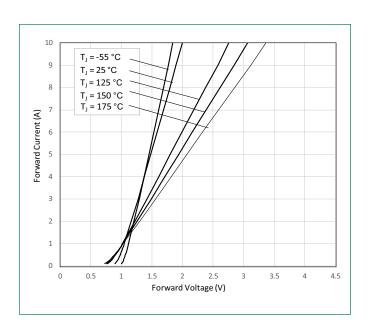


Figure 2: Typical Reverse Characteristics

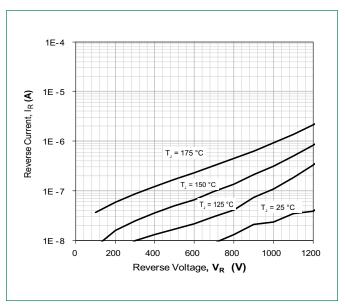




Figure 3: Power Derating

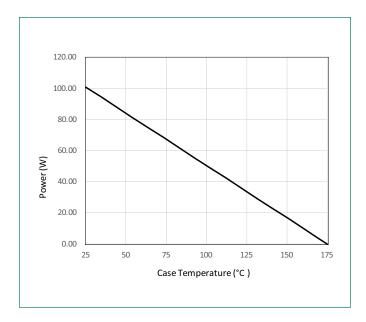


Figure 4: Current Derating

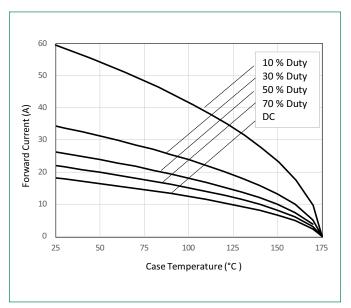


Figure 5: Capacitance vs. Reverse Voltage

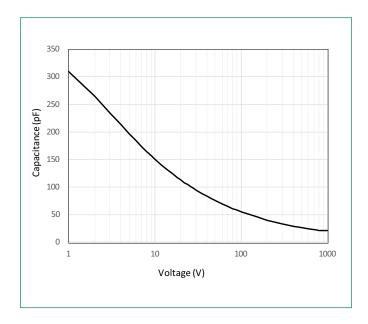
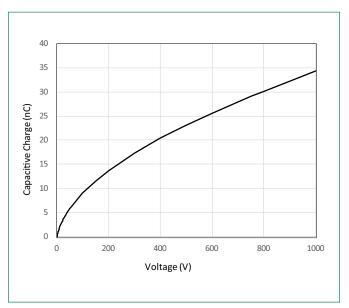


Figure 6: Capacitive Charge vs. Reverse Voltage



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Figure 7: Stored Energy vs. Reverse Voltage

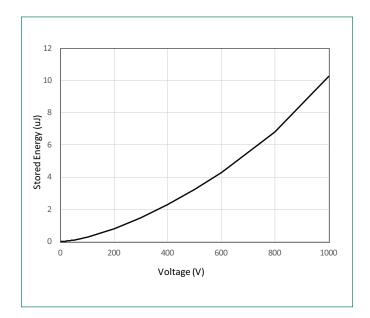
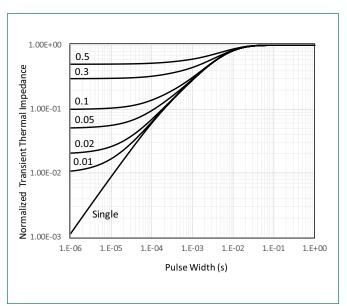
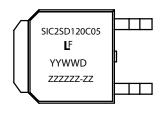


Figure 8: Transient Thermal Impedance



Part Numbering and Marking System



SIC	= SiC Diode
2	= Gen2
SD	= Schottky Diode
120	= Voltage Rating (1200 V)
С	= TO-252-2L (DPAK)
05	= Current Rating (5 A)
YY	= Year
WW	= Week

ZZZZZZ-ZZ = Lot Number

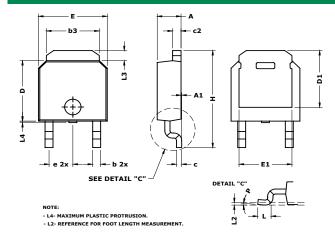
= Special code (fixed)

Packing Options

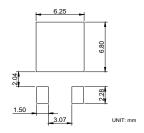
Part Number Marking		Packing Mode	M.O.Q
LSIC2SD120C05	SIC2SD120C05	Tape and Reel	2500



Dimensions TO-252-2L (DPAK)

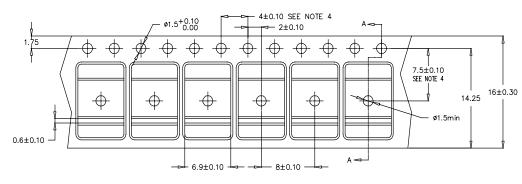


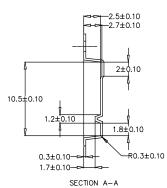
Recommended Solder Pattern Layout



Symbol	Inches			Millimeters			
Cyrribor	Min	Nom	Max	Min	Nom	Max	
Α	0.085	0.090	0.095	2.16	2.29	2.41	
A1	0	0.003	0.005	0	0.08	0.13	
b	0.025	0.030	0.035	0.64	0.76	0.89	
b3	0.195	0.200	0.215	4.95	5.08	5.46	
С	0.018	0.020	0.024	0.46	0.51	0.61	
C2	0.018	0.032	0.035	0.46	0.81	0.89	
D	0.235	0.240	0.245	5.97	6.10	6.22	
D1	0.205	-	-	5.21	-	-	
Е	0.250	0.260	0.265	6.35	6.60	6.73	
E1	0.170	-	-	4.32	-	-	
е	0.090 BSC			2.29 BSC			
Н	0.370	0.387	0.410	9.40	9.83	10.41	
L	0.040	0.045	0.050	1.02	1.14	1.27	
L2	0.010 BSC			0.25 BSC			
L3	0.035	-	0.050	0.89	-	1.27	
L4	0	-	0.006	0	-	0.15	
Р	0°	-	8°	0°	-	8°	

Carrier Tape & Reel Specification TO-252-2L (DPAK)





- Material: Black Conductive Polysterene
 10 sprocket hole pitch cumulative tolerance ± 0.20
 3. Camber not to exceed 1 mm in 100 mm.
 4 Pocket position relative to sprocket hole measured as true position of pocket, not pocket hole.
 5. Device orientation: TRL (leads perpendicular to the sprocket)

- 6. General tolerance is \pm 0.10 mm unless otherwise specified.

COVER TAPE SPECS:

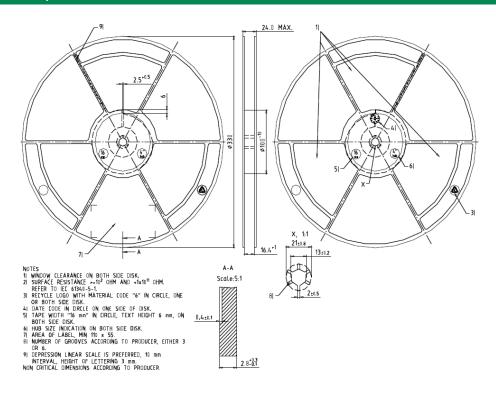
Width : 13.5 mm

: less than 1.2x10¹² ohms/square Base Material Transparent polyester, static dissipative

: Polyethylene Adhesive Laver Total Thickness : 60 Micron Tensile Strength : 4-6 kg/mm² : 91% Elongation Tearing Strength : 11 kg/mm² : 2 years Shelf life

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